

## < C band internally matched power GaAs FET >

# **MGFC36V5964A**

5.9 - 6.4 GHz BAND / 4W

#### **DESCRIPTION**

The MGFC36V5864A is an internally impedance-matched GaAs power FET especially designed for use in 5.9 - 6.4 GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

#### **FEATURES**

Internally matched to 50(ohm) system

· High output power

P1dB=4W (TYP.) @f=5.9 - 6.4GHz

• High power gain

GLP=10.0dB (TYP.) @f=5.9 - 6.4GHz

• High power added efficiency

P.A.E.=30% (TYP.) @f=5.9 - 6.4GHz

• Low distortion [item -51]

IM3=-45dBc (Typ.) @Po=25.0dBm S.C.L

#### **APPLICATION**

• item 01: 5.9 - 6.4 GHz band microwave high power amplifier

• item 01: 5.9 - 6.4 GHz band digital radio communication

### **QUALITY**

• IG

### RECOMMENDED BIAS CONDITIONS

• VDS=10V • ID=1.2A • RG=100ohm Refer to Bias Procedure

#### Absolute maximum ratings (Ta=25°C)

3- (								
Symbol	Parameter	Ratings	Unit					
VGDO	Gate to drain breakdown voltage	-15	V					
VGSO	Gate to source breakdown voltage	-15	V					
ID	Drain current	3.75	Α					
IGR	Reverse gate current	-10	mA					
IGF	Forward gate current	21	mA					
PT *1	Total power dissipation	25	W					
Tch	Cannel temperature	175	ç					
Tstg	Storage temperature	-65 to +175	°C					

\*1 : Tc=25°C

Symbol	Parameter	Test conditions		Limits		
			Min.	Тур.	Max.	
IDSS	Saturated drain current	VDS=3V, VGS=0V	-	-	3.75	Α
gm	Trans conductance	VDS=3V, ID=1.1A	-	1	-	S
VGS(off)	Gate to source cut-off voltage	VDS=3V,ID=10mA	-	-	-4.5	V
P1dB	Output power at 1dB gain compression	VDS=10V,ID(RF off)=1.2A	35	36	-	dBm
GLP *2	Linear Power Gain	f=5.9 – 6.4GHz	9	10	-	dB
P.A.E.	Power added efficiency	Pin=20dBm *2	-	30	-	%
ID	Drain current		-	-	1.8	Α
IM3 *3	3rd order IM distortion		-42	-45-	-	dBc
Rth(ch-c) *4	Thermal resistance	delta Vf method	-	5	6	°C/W

<sup>\*3 :</sup>item -51, 2 tone test,Po=25.0dBm Single Carrier Level ,f=6.4GHz,delta f=10MHz

**∐** (3) 10.7 17.0+/-0.2 GATE SOURCE (FLANGE) DRAIN GF-8

21.0+/-0.3

Unit: millimeters

**OUTLINE DRAWING** 

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<sup>\*4 :</sup>Channel-case

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